

# PI5V330

## Low On-Resistance Wideband/Video Quad 2-Channel Mux/DeMux

## Features

- · High-performance solution to switch between video sources
- Wide bandwidth: 400 MHz (typical)
- Low On-Resistance:  $5\Omega$  (typical)
- Low crosstalk at 10 MHz: -56dB
- Ultra-low quiescent power (0.1µA typical)
- Single supply operation: +5.0V
- Packaging (Pb-free & Green Available):
  16-pin 150-mil wide plastic SOIC (W)
  - 16-pin 150-mil wide plastic SOIC (W) - 16-pin 150-mil wide plastic QSOP (Q)

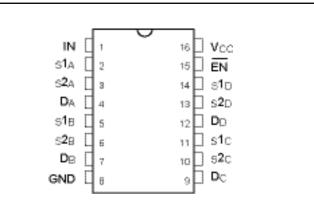
## Description

Pericom Semiconductor's PI5V330 is a true bidirectional Quad 2-channel multiplexer/demultiplexer recommended for both RGB and composite video switching applications. The video switch can be driven from a current output RAMDAC or voltage output composite video source.

Low On-Resistance and wide bandwidth make it ideal for video and other applications. Also this device has exceptionally high current capability which is far greater than most analog switches offered today. A single 5V supply is all that is required for operation.

The PI5V330 offers a high-performance, low-cost solution to switch between video sources. The application section describes the PI5V330 replacing the HC4053 multiplier and buffer/ amplifier.

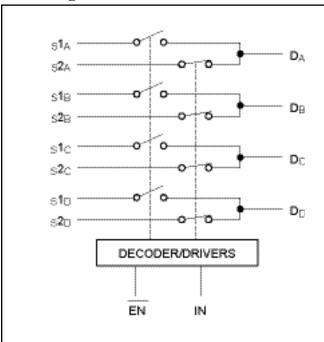
## **Pin Configuration**



### **Pin Description**

| Pin Name   | Description      |
|--|------------------|
| s1 <sub>A</sub> , s1 <sub>B</sub> , s1 <sub>C</sub> , s1 <sub>D</sub><br>s2 <sub>A</sub> , s2 <sub>B</sub> , s2 <sub>C</sub> , s2 <sub>D</sub> | Analog Video I/O |
| IN   | Select Input     |
| ĒN   | Enable           |
| D <sub>A</sub> , D <sub>B</sub><br>D <sub>C</sub> , D <sub>D</sub>   | Analog Video I/O |
| GND  | Ground           |
| V <sub>CC</sub>  | Power            |

## **Block Diagram**



#### **Truth Table**

| ĒN | IN | ON Switch  |  |  |
|----|----|--|--|--|
| 0  | 0  | S <sup>1</sup> A, S <sup>1</sup> B, S <sup>1</sup> C, S <sup>1</sup> D |  |  |
| 0  | 1  | s2 <sub>A</sub> , s2 <sub>B</sub> , S2 <sub>C</sub> , s2 <sub>D</sub>  |  |  |
| 1  | X  | Disabled   |  |  |



#### **Maximum Ratings**

(Above which the useful life may be impaired. For user guidelines, not tested.)

| Storage Temperature65°C to +150°C  |
|--|
| Ambient Temperature with Power Applied40°C to +85°C                              |
| Supply Voltage to Ground Potential (Inputs & V <sub>CC</sub> Only)–0.5V to +7.0V |
| Supply Voltage to Ground Potential (Outputs & D/O Only)-0.5V to +7.0V            |
| DC Input Voltage0.5V to +7.0V  |
| DC Output Current  |
| Power Dissipation  |

Stresses greater than those listed under MAXIMUM RAT-INGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

Note:

#### **DC Electrical Characteristics** (Over the Operating Range, $TA = -40^{\circ}C$ to $+85^{\circ}C$ , $VCC = 5V \pm 5\%$ )

| Parameters       | Description                         | Test Conditions <sup>(1)</sup>                     | Min. | Typ. <sup>(2)</sup> | Max. | Units |
|------------------|-------------------------------------|--|------|---------------------|------|-------|
| VANALOG          | Analog Signal Range                 |  | 0    |                     | 2.0  |       |
| V <sub>IH</sub>  | Input HIGH Voltage                  | Guaranteed Logic HIGH Level                        | 2.0  |                     |      | V     |
| V <sub>IL</sub>  | Input LOW Voltage                   | Guaranteed Logic LOW Level                         | -0.5 |                     | 0.8  |       |
| I <sub>IH</sub>  | Input HIGH Current                  | $V_{CC} = Max., V_{IN} = V_{CC}$                   |      |                     | ±1   |       |
| I <sub>IL</sub>  | Input LOW Current                   | $V_{CC} = Max., V_{IN} = GND$                      |      |                     | ±1   | μA    |
| Io               | Analog Output Leakage Current       | $0 \le S1$ , S2 or $D \le V_{CC}$ , Switch OFF     |      |                     | ±1   |       |
| V <sub>IK</sub>  | Clamp Diode Voltage                 | $V_{CC} = Min., I_{IN} = -18mA$                    | -0.7 | -1.2                |      | V     |
| $V_{\mathrm{H}}$ | Input Hysteresis at Control Pins    |  |      | 150                 |      | mV    |
| R <sub>ON</sub>  | Switch On-Resistance <sup>(3)</sup> | $V_{CC} = Min., V_{IN} = 1.0V,$<br>$I_{ON} = 13mA$ |      | 5                   | 7    |       |
|                  |                                     | $V_{CC} = Min., V_{IN} = 2.0V,$<br>$I_{ON} = 26mA$ |      | 7                   | 10   | Ω     |

Notes:

1. For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device type.

2. Typical values are at  $V_{CC} = 5.0V$ ,  $T_A = 25^{\circ}C$  ambient and maximum loading.

3. Measured by the voltage drop between S1, S2, and D I/O pins at indicated current through the switch. On-Resistance is determined by the lower of the voltages on the S1, S2, and D I/O pins.

| Parameters        | Description              | Test Conditions                                 | Min. | Тур. | Max. | Unit |
|-------------------|--------------------------|---|------|------|------|------|
| t <sub>ON</sub>   | Turn On Time             | $R_L = 75\Omega$ , $C_L = 20_{PF}$ , See Fig. 4 |      | 2.5  | 5    | na   |
| t <sub>OFF</sub>  | Turn Off Time            | $R_L = 75\Omega$ , $C_L = 20_{PF}$ , See Fig. 4 |      | 1.1  | 5    | ns   |
| $B_W^{(1)}$       | -3 dB Bandwidth          | See Fig. 5                                      |      |      | 400  | MHz  |
| X <sub>TALK</sub> | Crosstalk                | 10MHz, See Fig. 5                               |      | -80  |      | dB   |
| $C_{IN}^{(1)}$    | Input/Enable Capacitance | $V_{IN} = 0V$ , f = 1 MHz                       |      |      | 6    |      |
| $C_{OFF}^{(1)}$   | Capacitance, Switch Off  | $V_{IN} = 0V, f = 1 MHz$                        |      |      | 6    | pF   |
| $C_{ON}^{(1)}$    | Capacitance, Switch On   | $V_{IN} = 0V$ , f = 1 MHz                       |      |      | 9    |      |
| O <sub>IRR</sub>  | Off Isolation            | 10MHz, See Fig 5                                |      | -56  |      | dB   |

#### **Dynamic Characteristics** (Over the Operating Range, $T_A = -40^{\circ}C$ to $+85^{\circ}C$ , $V_{CC} = 5V \pm 5\%$ )

Notes:

1. This parameter is determined by device characterization but is not production tested.

#### **Power Supply Characteristics**

| Parameters         | Description  | Test Conditions <sup>(1)</sup>  |                      | Min. | <b>Typ</b> <sup>(2)</sup> | Max. | Units      |
|--------------------|--|---|----------------------|------|---------------------------|------|------------|
| I <sub>CC</sub>    | Quiescent Power<br>Supply Current                  | $V_{CC} = Max.$   | IN = GND or $V_{CC}$ |      | 0.1                       | 3.0  | μΑ         |
| $\Delta_{\rm ICC}$ | Supply Current per Input<br>@ TTL HIGH             | $V_{CC} = Max.$   | $IN = 3.4V^{(3)}$    |      |                           | 2.5  | mA         |
| I <sub>CCD</sub>   | Supply Current per Input<br>per MHz <sup>(4)</sup> | $V_{CC} = Max., S1, S2 and D$<br>Pins Open $\overline{EN} = GND$<br>Control Input Toggling<br>50%Duty Cycle |                      |      |                           | 0.25 | mA/<br>MHz |

Notes:

1. For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device.

2. Typical values are at  $V_{CC} = 5.0V$ ,  $+25^{\circ}C$  ambient.

3. Per TTL driven input ( $V_{IN} = 3.4V$ , control inputs only); S1, S2, and D pins do not contribute to I<sub>CC</sub>.

4. This current applies to the control inputs only and represent the current required to switch internal capacitance at the specified frequency. The S1, S2, and D I/O pins generate no significant AC or DC currents as they transition. This parameter is not tested, but is guaranteed by design.



#### Definitions

| Symbol                             | Description   |
|------------------------------------|---|
| R <sub>ON</sub>                    | Resistance between source and drain with switch in the ON state.  |
| IO                                 | Output leakage current measured at S1, S2, and D with the switch OFF.   |
| V <sub>IN</sub>                    | Digital voltage at the IN pin that selects between S1 and S2 analog inputs.   |
| V <sub>EN</sub>                    | A voltage that ENABLES the chip.  |
| C <sub>IN</sub>                    | Capacitance at the digital inputs.  |
| C <sub>OFF</sub>                   | Capacitance at analog I/O (S1, S2, D) with switch OFF.  |
| C <sub>ON</sub>                    | Capacitance at analog I/O (S1, S2, D) with switch ON.   |
| V <sub>IH</sub>                    | Minimum input voltage for logic HIGH.   |
| V <sub>IL</sub>                    | Minimum input voltage for logic LOW.  |
| I <sub>IH</sub> (I <sub>IL</sub> ) | Input current of the digital input.   |
| t <sub>ON</sub>                    | Propagation delay measured between 50% of the digital input to 90% of the analog output when switch is turned ON. The peak analog voltage is 0.714V.  |
| t <sub>OFF</sub>                   | Propagation delay measured between 50% of the digital input to 90% of the analog output when switch is turned OFF. The peak analog voltage is 0.714V. |
| $\mathrm{B}_{\mathrm{W}}$          | Frequency response of the switch in the ON state measured at 3dB down.  |
| X <sub>TALK</sub>                  | Is an unwanted signal coupled from channel to channel. Measured in –dB. XTALK = 20 LOG VOUT/VIN. This is non-adjacent crosstalk.                      |
| O <sub>IRR</sub>                   | Off isolation is the resistance (measured in –dB) between the input and output with the switch off (NO).  |



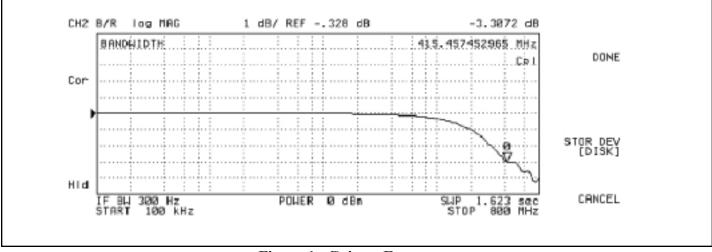
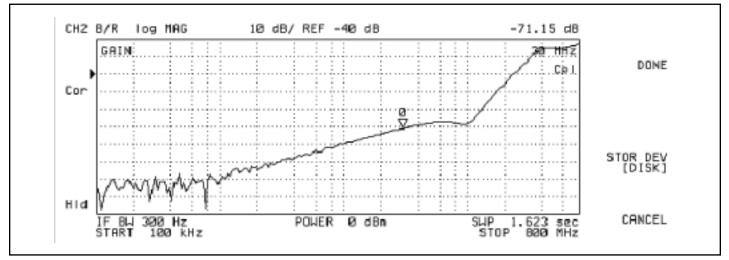


Figure 1. Gain vs Frequency



**Figure 2. Off Isolation vs Frequency** 



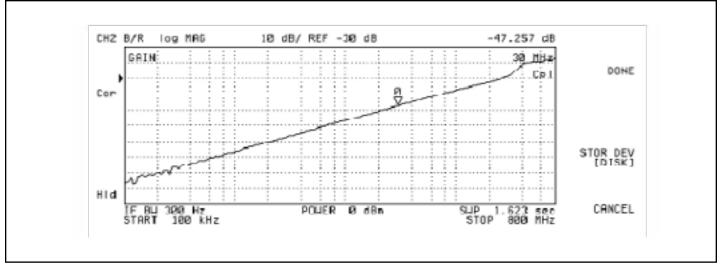
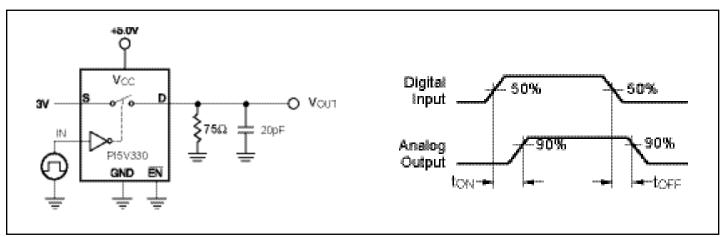
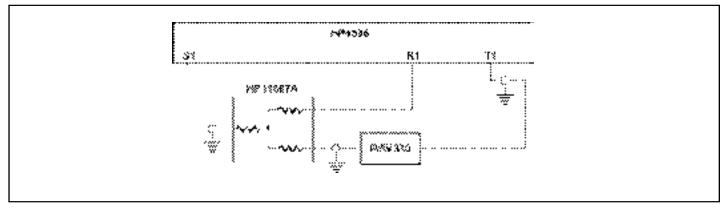


Figure 3. Crosstalk vs Frequency



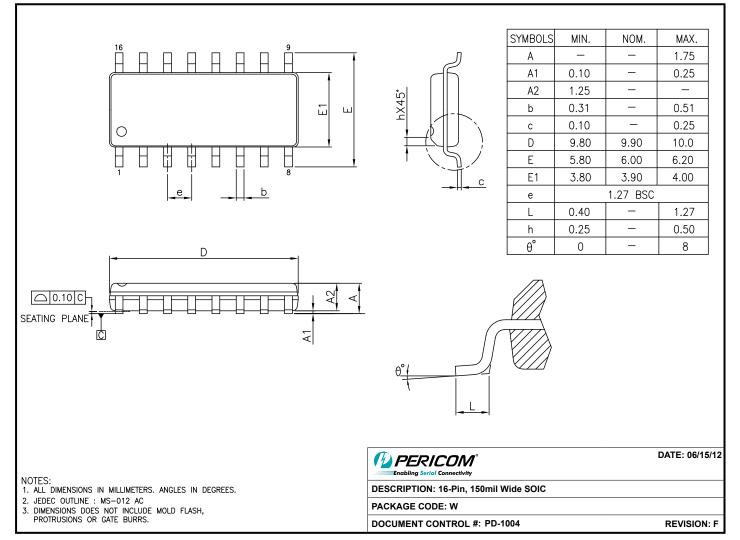
### Figure 4. Switching Time







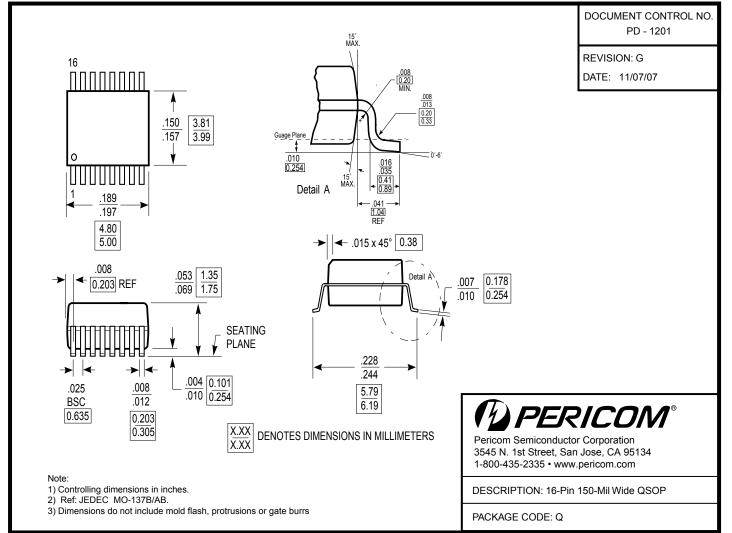
## Packaging Mechanical: 16-pin SOIC (W)



2012-0398



## Packaging Mechanical: 16-pin QSOP (Q)



#### **Ordering Information**

| Ordering Code | Package Code | Package Description                               |
|---------------|--------------|---|
| PI5V330W      | W            | 16-pin 150-mil wide plastic SOIC                  |
| PI5V330WE     | W            | Pb-free & Green, 16-pin 150-mil wide plastic SOIC |
| PI5V330Q      | Q            | 16-pin 150-mil wide plastic QSOP                  |
| PI5V330QE     | Q            | Pb-free & Green, 16-pin 150-mil wide plastic QSOP |

#### Notes:

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1. Thermal characteristics can be found on the company web site at www.pericom.com/packaging/

Pericom Semiconductor Corporation • 1-800-435-2336 • www.pericom.com

单击下面可查看定价,库存,交付和生命周期等信息

>>Diodes Incorporated(达迩科技(美台))